查询SN54LV14A 供应商

<u>捷多邦,专业PCB打样工厂SN5441/144A</u> HEX SCHMITT-TRIGGER INVERTERS

SN54LV14A ... J OR W PACKAGE

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- EPIC ™ (Enhanced-Performance Implanted CMOS) Process
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot) >2.3 V at V_{CC} = 3.3 V, T_A = 25°C
- 2-V to 5.5-V V_{CC} Operation
- Support Mixed-Mode Voltage Operation on All Ports
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Package Options Include Plastic Small-Outline (D, NS), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), and Thin Shrink Small-Outline (PW) Packages, Ceramic Flat (W) Packages, Chip Carriers (FK), and DIPs (J)

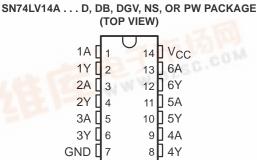
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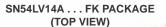
These hex Schmitt-trigger inverters are designed for 2-V to 5.5-V V_{CC} operation.

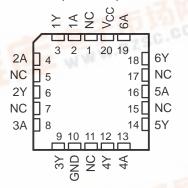
The 'LV14A devices contain six independent inverters. These devices perform the Boolean function $Y = \overline{A}$.

The SN54LV14A is characterized for operation over the full military temperature range of -55° C to 125°C. The SN74LV14A is characterized for operation from -40° C to 85°C.

FUNCTION TABLE (each inverter)									
T OUTPUT Y									
L									
Н									







NC – No internal connection



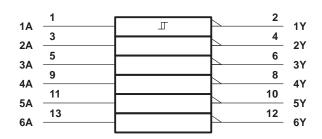
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logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, DB, DGV, J, NS, PW, and W packages.

logic diagram, each inverter (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage range, V _{CC} Input voltage range, V _I (see Note 1)		
Voltage range applied to any output in the high		
or power-off state, V _O (see Note 1)		–0.5 V to 7 V
Output voltage range, V _O (see Notes 1 and 2)		$\dots -0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, IIK (VI < 0)		
Output clamp current, I_{OK} (V _O < 0 or V _O > V _C		
Continuous output current, $I_O (V_O = 0 \text{ to } V_{CC})$		
Continuous current through V _{CC} or GND		
Package thermal impedance, θ_{JA} (see Note 3)		
	DB package	
	DGV package	
	NS package	
	PW package	113°C/W
Storage temperature range, T _{stg}		

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stressratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. This value is limited to 5.5 V maximum.

3. The package thermal impedance is calculated in accordance with JESD 51.



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			SN54L	V14A	SN74	_V14A	
			MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage		2	5.5	2	5.5	V
		$V_{CC} = 2 V$	1.5		1.5		
v	High-level input voltage	V_{CC} = 2.3 V to 2.7 V	$V_{CC} \times 0.7$		$V_{CC} \times 0.7$		v
VIH	High-level linput voltage	$V_{CC} = 3 V \text{ to } 3.6 V$	$V_{CC} \times 0.7$		$V_{CC} \times 0.7$		Ň
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	$V_{CC} \times 0.7$		$V_{CC} \times 0.7$		
		$V_{CC} = 2 V$		0.5		0.5	
v	Low-level input voltage	V_{CC} = 2.3 V to 2.7 V	,	V _{CC} ×0.3		$V_{CC} \times 0.3$	v
VIL	Low-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$,	VCC×0.3		$V_{CC} \times 0.3$	v
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$,	V _{CC} × 0.3		$V_{CC} \times 0.3$	
VI	Input voltage		0	5.5	0	5.5	V
VO	Output voltage		0 0	Vcc	0	V _{CC}	V
		$V_{CC} = 2 V$	PP C	-50		-50	μA
10.1	High lovel output ourrest	V_{CC} = 2.3 V to 2.7 V		-2		-2	
ЮН	High-level output current	$V_{CC} = 3 V \text{ to } 3.6 V$		-6		-6	mA
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-12		-12	
		$V_{CC} = 2 V$		50		50	μA
		V_{CC} = 2.3 V to 2.7 V		2		2	
IOL	Low-level output current	$V_{CC} = 3 V \text{ to } 3.6 V$		6		6	mA
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		12		12	
TA	Operating free-air temperature		-55	125	-40	85	°C

recommended operating conditions (see Note 4)

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	TEAT CONDITIONS		SN	54LV14A	SN	74LV14	A	
PARAMETER	TEST CONDITIONS	Vcc	MIN	TYP MAX	MIN	TYP	MAX	UNIT
V _{T+}		2.5 V		1.75			1.75	
Positive-going		3.3 V		2.31			2.31	V
threshold		5 V		3.5			3.5	
V _T		2.5 V	0.75		0.75			
Negative-going		3.3 V	0.99		0.99			V
threshold		5 V	1.5		1.5			
		2.5 V	0.25	1	0.25		1	
ΔV_T Hysteresis (V _{T+} – V _{T-})		3.3 V	0.33	1.32	0.33		1.32	V
		5 V	0.5	2	0.5		2	
	I _{OH} = -50 μA	2 V to 5.5 V	V _{CC} -0.7		V _{CC} -0.1			
VOH	$I_{OH} = -2 \text{ mA}$	2.3 V	2	2	2			V
VOH	I _{OH} = -6 mA	3 V	2.48	5	2.48			v
	I _{OH} = -12 mA	4.5 V	3.8	>	3.8			
	I _{OL} = 50 μA	2 V to 5.5 V	Q.	0.1			0.1	
V _{OL}	I _{OL} = 2 mA	2.3 V		0.4			0.4	V
VOL	I _{OL} = 6 mA	3 V		0.44			0.44	v
	I _{OL} = 12 mA	4.5 V		0.55			0.55	
lı	$V_I = V_{CC}$ or GND	0 V to 5.5 V		±1			±1	μΑ
Icc	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	5.5 V		20			20	μΑ
loff	$V_I \text{ or } V_O = 0 \text{ to } 5.5 \text{ V}$	0 V		5			5	μΑ
Ci	VI = V _{CC} or GND	3.3 V		2.3		2.3		рF
		5 V		2.3		2.3		μ

switching characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	Α = 25°C	;	SN54LV	'14A	SN74L	V14A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t _{pd}	A	Y	C _L = 15 pF		10.2*	19.7*	A P	22*	1	22	ns
^t pd	А	Y	C _L = 50 pF		13.3	24	Q 1	27	1	27	ns

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	_ = 25°C	;	SN54LV1	4A	SN74L	V14A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MINST	XAN	MIN	MAX	UNIT
^t pd	A	Y	C _L = 15 pF		7.3*	12.8*	1 * 1	5.9*	1	15	ns
^t pd	A	Y	C _L = 50 pF		9.6	16.3	21	19.4	1	18.5	ns

* On products compliant to MIL-PRF-38535, this parameter is not production tested.



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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	₄ = 25°C	;	SN54LV14	Α	SN74L	V14A	UNIT
	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MINSM	AX	MIN	MAX	UNIT
^t pd	A	Y	C _L = 15 pF		5.1*	8.6*	A-1-1-1	10*	1	10	ns
^t pd	А	Y	C _L = 50 pF		6.7	10.6	°1	12	1	12	ns

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, V_{CC} = 3.3 V, C_L = 50 pF, T_A = 25°C (see Note 5)

	PARAMETER				UNIT
	PARAMETER	MIN	TYP	MAX	UNIT
VOL(P)	Quiet output, maximum dynamic V _{OL}		0.2	0.8	V
VOL(V)	Quiet output, minimum dynamic V _{OL}		-0.1	-0.8	V
VOH(V)	Quiet output, minimum dynamic V _{OH}		3.1		V
VIH(D)	High-level dynamic input voltage	2.31			V
VIL(D)	Low-level dynamic input voltage			0.99	V

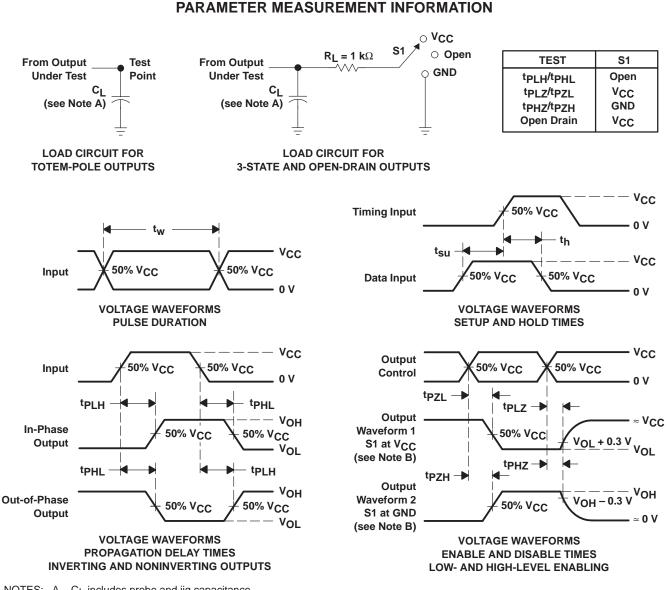
NOTE 5: Characteristics are for surface-mount packages only.

operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER		TEST CONDITIONS			UNIT
C _{pd}	Power dissipation capacitance	$C_{\rm L} = 50 \rm pE$	f = 10 MHz	3.3 V	8.8	рF
		C _L = 50 pF,	1 = 10 10112	5 V	9.6	ρr



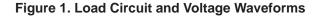
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NOTES: A. CL includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_Q = 50 Ω, t_f ≤ 3 ns, t_f ≤ 3 ns.

- D. The outputs are measured one at a time with one input transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. tpHL and tpLH are the same as t_{pd} .





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